

## Lab 9

# Bipolar Devices and Applications

## Introduction

In this lab, I will be looking at developing different measurement methods for extracting device parameters of the Bipolar Junction Transistor and investigating the applications of discrete BJTs.

## Part 1

In this part I looked into comparing the small-signal model parameters  $g_m$ ,  $g_0$ , and  $g_{\pi}$  with those given in one of the data sheet for the PN2222 provided by onsemi.com.

I used the Semiconductor Parameter Analyzer to obtain the small signal parameters of the BJT in my lab kit and compare them to the parameters from the data sheet.

The figure blow shows some of the data obtained by the Semiconductor Parameter Analyzer.

A	B	C	D	E	F	G	H	I	J	K	L	M	N
Index	Ibase	Ibase	Ibase(A)		Vcollector	Vcollector(V)		Icollector	Icollector(A)		Vbase	Vbase(V)	
1		10.00	1.00E-05	uA	0		V	-9.69331	-9.69331E-06	uA	521.524	5.22E-01	mV
2		10	1.00E-05	uA	50	5.00E-02	mV	72.2025	7.22025E-05	uA	569.382	5.69E-01	mV
3		10	1.00E-05	uA	100	1.00E-01	mV	441.147	0.000441147	uA	609.99	6.10E-01	mV
4		10	1.00E-05	uA	150	1.50E-01	mV	1.069445	0.001069445	mA	632.346	6.32E-01	mV
5		10	1.00E-05	uA	200	2.00E-01	mV	1.35443	0.00135443	mA	638.466	6.38E-01	mV
6		10	1.00E-05	uA	250	2.50E-01	mV	1.41008	0.00141008	mA	639.512	6.40E-01	mV
7		10	1.00E-05	uA	300	3.00E-01	mV	1.41905	0.00141905	mA	639.662	6.40E-01	mV
8		10	1.00E-05	uA	350	3.50E-01	mV	1.42078	0.00142078	mA	639.692	6.40E-01	mV
9		10	1.00E-05	uA	400	4.00E-01	mV	1.42147	0.00142147	mA	639.694	6.40E-01	mV
10		10	1.00E-05	uA	450	4.50E-01	mV	1.42203	0.00142203	mA	639.7	6.40E-01	mV
11		10	1.00E-05	uA	500	5.00E-01	mV	1.42247	0.00142247	mA	639.702	6.40E-01	mV
12		10	1.00E-05	uA	550	5.50E-01	mV	1.42293	0.00142293	mA	639.702	6.40E-01	mV
13		10	1.00E-05	uA	600	6.00E-01	mV	1.42326	0.00142326	mA	639.714	6.40E-01	mV
14		10	1.00E-05	uA	650	6.50E-01	mV	1.42368	0.00142368	mA	639.712	6.40E-01	mV
15		10	1.00E-05	uA	700	7.00E-01	mV	1.42402	0.00142402	mA	639.71	6.40E-01	mV
16		10	1.00E-05	uA	750	7.50E-01	mV	1.42443	0.00142443	mA	639.716	6.40E-01	mV
17		10	1.00E-05	uA	800	8.00E-01	mV	1.42473	0.00142473	mA	639.71	6.40E-01	mV
18		10	1.00E-05	uA	850	8.50E-01	mV	1.42514	0.00142514	mA	639.718	6.40E-01	mV
19		10	1.00E-05	uA	900	9.00E-01	mV	1.42548	0.00142548	mA	639.72	6.40E-01	mV
20		10	1.00E-05	uA	950	9.50E-01	mV	1.42587	0.00142587	mA	639.726	6.40E-01	mV
21		10	1.00E-05	uA	1	1.00E+00	V	1.42611	0.00142611	mA	639.73	6.40E-01	mV
22		10	1.00E-05	uA	1.05	1.05E+00	V	1.42644	0.00142644	mA	639.734	6.40E-01	mV
23		10	1.00E-05	uA	1.1	1.10E+00	V	1.42679	0.00142679	mA	639.728	6.40E-01	mV
24		10	1.00E-05	uA	1.15	1.15E+00	V	1.42705	0.00142705	mA	639.73	6.40E-01	mV
25		10	1.00E-05	uA	1.2	1.20E+00	V	1.42737	0.00142737	mA	639.734	6.40E-01	mV
26		10	1.00E-05	uA	1.25	1.25E+00	V	1.42769	0.00142769	mA	639.74	6.40E-01	mV
27		10	1.00E-05	uA	1.3	1.30E+00	V	1.42798	0.00142798	mA	639.74	6.40E-01	mV
28		10	1.00E-05	uA	1.35	1.35E+00	V	1.42827	0.00142827	mA	639.738	6.40E-01	mV
29		10	1.00E-05	uA	1.4	1.40E+00	V	1.42858	0.00142858	mA	639.742	6.40E-01	mV
30		10	1.00E-05	uA	1.45	1.45E+00	V	1.42887	0.00142887	mA	639.746	6.40E-01	mV

Below are the calculations done to determine the values of my BJT's parameters.

$$\beta = h_f \quad h_{FE} = \beta$$

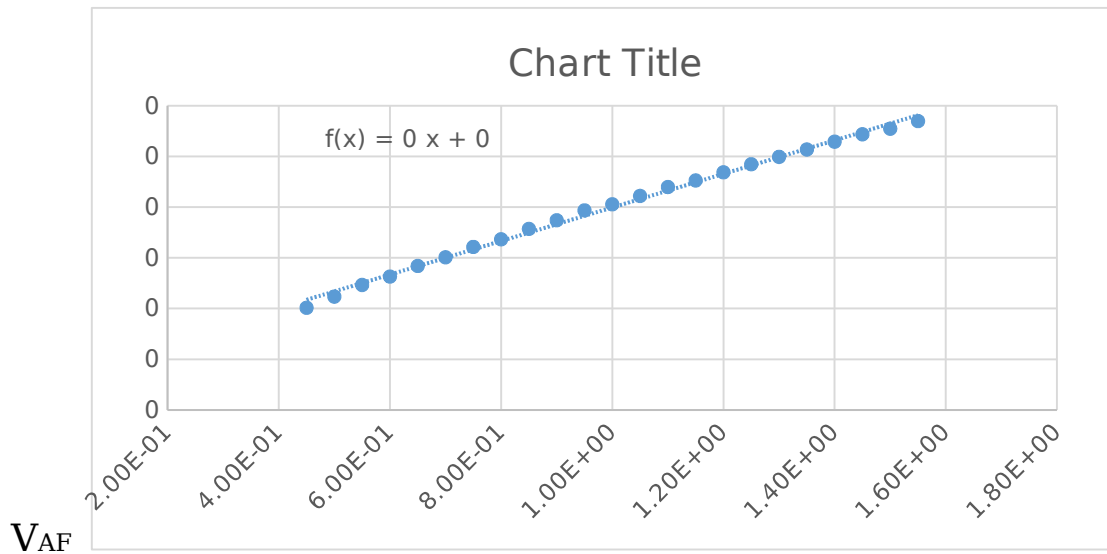
$$I_c = \beta I_B$$

$$\beta = \frac{I_c}{I_B} = \frac{0.00142587}{1 \times 10^{-5}} = 142.587$$

$$g_{\pi} = \frac{I_{CQ}}{\beta V_t} = \frac{0.00142587}{142.587 \times 26 \times 10^{-3}} = 2600$$

$$g_o = \frac{I_{CQ}}{V_{AF}} = \frac{0.00142587}{\left( \frac{0.0014}{7 \times 10^6} \right)} = 7.12935 \times 10^6$$

Below is the forward active plot. I used the slope to calculate the

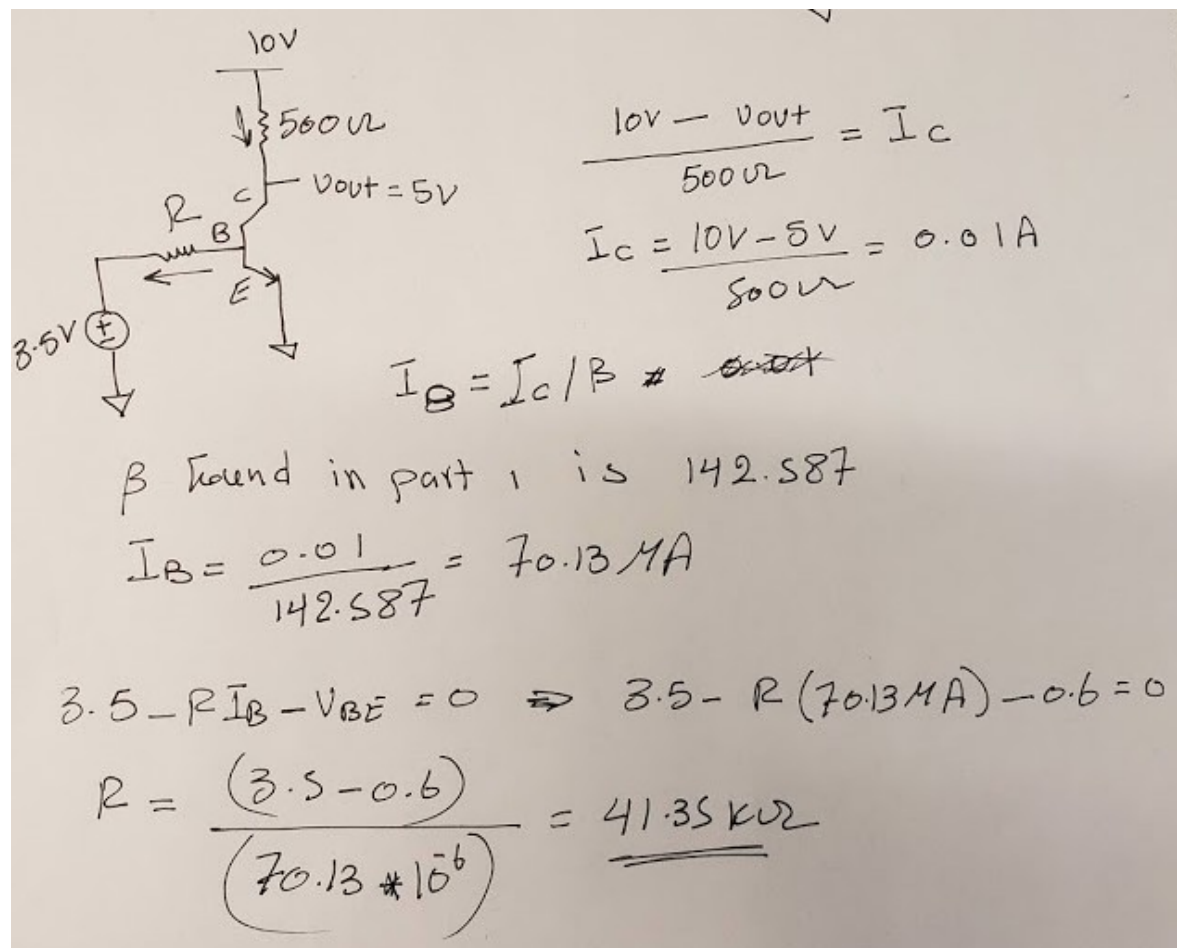


Below table shows the analyzer values VS the datasheet values

Parameter	Analyzer Value	Datasheet Value
$\beta = h_{fe}$	142.587	50-375
$g_{\pi} = h_{ie}$ (k.ohms)	2.7	2-8
$g_o = h_{oe}$ ( $\mu$ Mnos)	7.12935	5-200

## Part 2

Design a circuit that will drive a  $500\Omega$  load between  $0V$  and  $10V$  when a Boolean signal goes between  $0V$  and  $5V$ .



The diagram shows a BJT circuit where the base is driven by a  $3.5V$  source through a resistor  $R$ . The collector is connected to a  $10V$  supply and a  $500\Omega$  load. The emitter is grounded. The output voltage  $V_{out}$  is taken from the collector and is specified as  $5V$ .

$$\frac{10V - V_{out}}{500\Omega} = I_C$$

$$I_C = \frac{10V - 5V}{500\Omega} = 0.01A$$

$$I_B = I_C / \beta$$

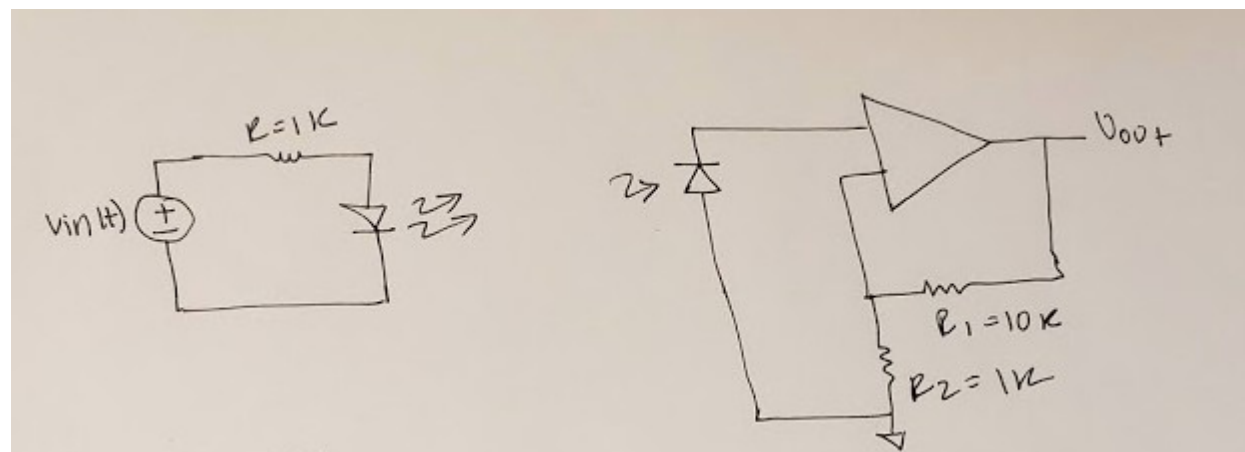
$\beta$  found in part 1 is  $142.587$

$$I_B = \frac{0.01}{142.587} = 70.13\mu A$$

$$3.5 - R I_B - V_{BE} = 0 \Rightarrow 3.5 - R(70.13\mu A) - 0.6 = 0$$

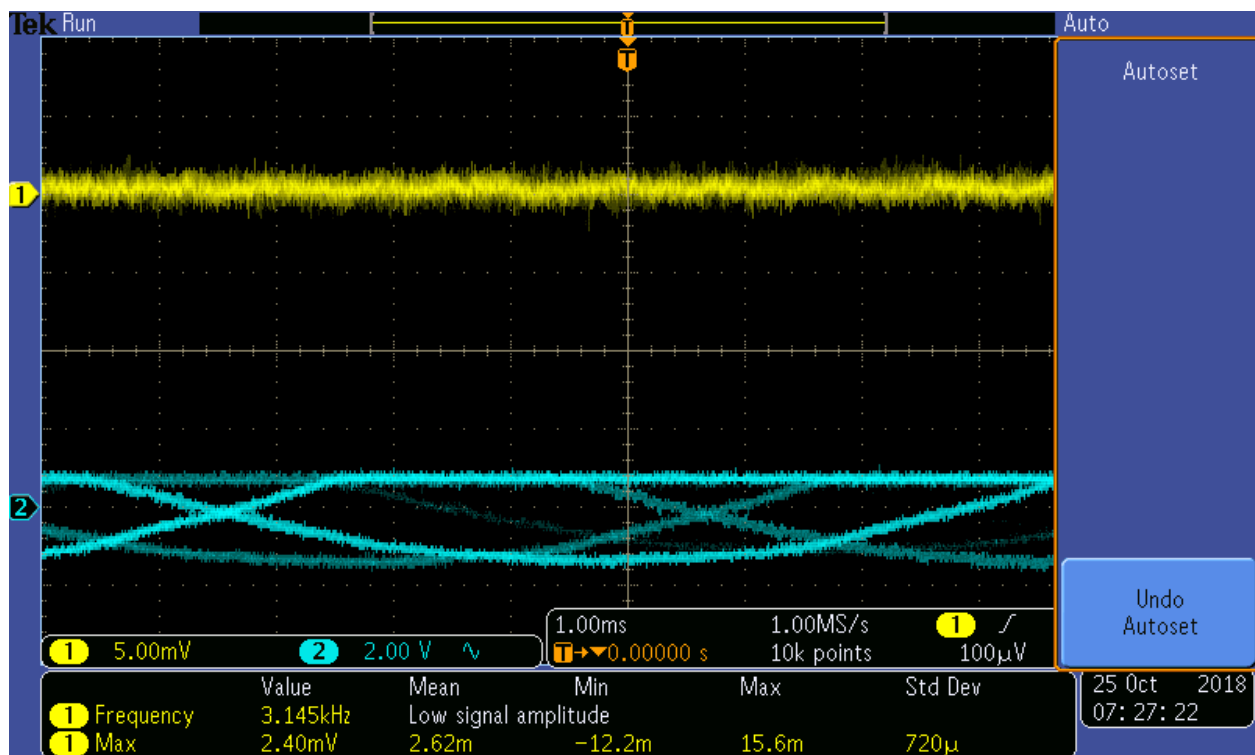
$$R = \frac{(3.5 - 0.6)}{(70.13 \times 10^{-6})} = \underline{\underline{41.35k\Omega}}$$

## Part 3



The circuit above showed the design of my wireless optical link that will transmit an audio (music) signal over at least 6 inches. As shown in the

figure below this design is composed of two circuits. The first circuit is the transmitter end which consists of a resistor and a photodiode. The audio signal is connected to  $v_{in}(t)$ . The receiver end is made of LM324 op amp, two (10k and 1k) resistors and photodiode receiver. The signal received across the photodiode was very small and needed to be amplified before it was connected to the speakers. I built a non-inverting amplifier with enough gain to amplify the sound received from the photodiode receiver. The graph below shows the input signal vs the output signal. of the design.



## Conclusion

This lab was very beneficial and fun at the same time. I looked at comparing the small-signal model parameters  $g_m$ ,  $g_0$ , and  $g_{\pi}$  with those given in one of the data sheet for the PN2222. I also looked at design a circuit that will drive a particular load using certain voltage. I designed a wireless optical link that will transmit an audio (music) signal over at least 6 inches.